ASSP For Power Supply Applications

Power Management 2-ch Switch IC

MB3842/MB3845

■ DESCRIPTION

The MB3842/3845 is a power management switch with built-in 2-channel low-on resistance (typ. $100 \text{m}\Omega$) switch. Output control is by means of a control signal, and the MB3842 is designed for high-active operation (output on when EN is Hi), while the MB3845 is designed for low-active operation (output on when $\overline{\rm EN}$ is low.) To provide adaptability to a variety of operations, the MB3842/3845 features low input voltage (V_{IN} > 2.5V) operation and stable low-on resistance independent of input voltage. The switching current limit can be set from

100mA to 600mA by using external resistance, and when overcurrent conditions are detected the OC output goes low to provide an external notification signal.

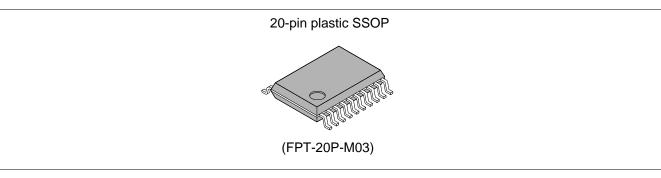
VIN is divided between the two channels, which operate independently of each other.

In addition, an off-state reverse current prevention function is provided to ensure accurate on/off switching action.

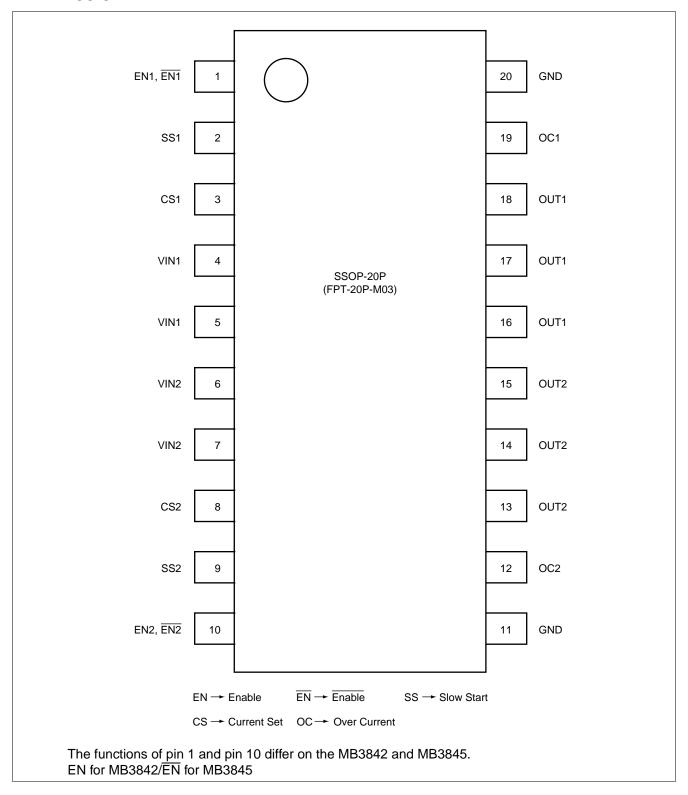
■ FEATURES

- Low on resistance switch (typ. $100 \text{m}\Omega$)
- Low input voltage operation (2.5 V to 5.5 V)
- Switch current (max. 0.6 A)
- 2.3V/2.1 V hysteresis 200 mV UVLO :VIN threshold
- EN 1.4V/1.6 V for MB3842, EN 1/2 V_{IN} for MB3845 ENABLE :EN threshold
 - EN < 0.8V for MB3842, $\overline{EN} = V_{IN}$ for MB3845 :Power supply current at output off = 0μ A
- External setting for soft start time and switch current limit.
- Over-temperature detection (switch latched off), over-current detection (not latched)
- OC pin flag set following overcurrent detection, over-temperature detection, or UVLO detection.
- Reverse current prevention at OFF (V_{IN} ≥ 1.5 V)
- Either channel may be operated alone.

■ PACKAGE



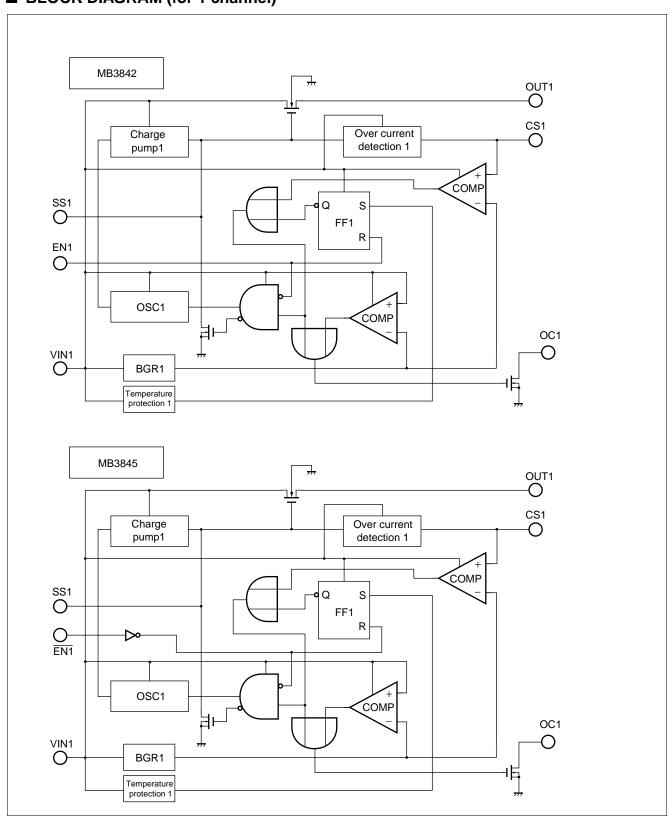
■ PIN ASSIGNMENT



■ PIN DESCRIPTION

| Pin no. | Symbol | Descriptions |
|-------------------------------|----------------|--|
| | EN (MB3842) | Control signal input pin. Set "H" to turn switch on, "L" to turn toff. At 0.8 V or less, the chip is in STBY state and current consumption is less than 1µA. "L" level is 1.4V (typ), "H" level is 1.6V (typ), with 200mV (typ) hysteresis. |
| 1/10 <u>EN</u> (MB3845) | | Control signal input pin. Set "L" to turn switch on, "H" to turn off. At "H" level = V_{IN} , the chip is in STBY state and current consumption is less than $1\mu A$. Normally used as CMOS inverter input, so that recommended use is "L" level at GND +0.5V or less, and "H" level is V_{IN} -0.5V or greater. |
| 2/9 | SS | Slow start setting pin. Used to adjust the switch on/off timing. Add external capacitance to delay operation. Leave open when not in use. In open mode voltages up to 12 V are present. Care should be taken in mounting to prevent leakage current generation because high impedance is required. |
| 3/8 | CS | Current limit setting pin. The limit current level is set by connecting this pin to external resistance. |
| 4/5/6/7 | VIN | Switch output pin. An UVLO (VIN power monitor function) is provided so that when VIN reaches 2.3V (typ.) or higher the OC pin voltage goes to "H" level. Also if the VIN voltage drops to 2.1 V (typ.) or lower the OC output goes to "L" state. 200mV (typ) hysteresis is provided. |
| 11/20 | GND | Ground pin. |
| 12/19 | ОС | External notification pin. When the switch is in on mode this pin normally outputs a "H" level signal, but changes to "L" level when an overcurrent, overtemperature, or UVLO condition is detected. This is an open drain connection, and should be pulled up to high potential using resistance. |
| 13/14/15 16/17/18 | OUT | Switching output pin.(N-ch MOSFET source) |

■ BLOCK DIAGRAM (for 1 channel)



■ ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Condition | Rat | Unit | | |
|---------------------|----------------|------------|-------------|------|----|--|
| Farameter | Symbol | | Max. | Min. | | |
| Input voltage | Vin | _ | -0.3 | 7.0 | V | |
| ENABLE voltage | VEN | _ | -0.3 | 7.0 | V | |
| Switch current | Isw | _ | _ | 1.8 | Α | |
| Power dissipation | P _D | Ta = +85°C | _ | 216 | mW | |
| Storage temperature | Тѕтс | _ | - 55 | +125 | °C | |

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

| Parameter | Symbol | bol Condition | | Value | | | | |
|-----------------------|----------|---|------|-------|------|------|--|--|
| Farameter | Syllibol | Condition | Min. | Тур. | Max. | Unit | | |
| Input voltage | VIN | _ | 2.5 | 5.0 | 5.5 | V | | |
| ENABLE voltage | VEN | Ven ≤ Vin | 0 | _ | 5.5 | V | | |
| Switch current | Isw | V _{IN} = 2.5 V to 5.5 V | _ | _ | 0.6 | Α | | |
| SS pin capacitance | Css* | _ | _ | _ | 10 | nF | | |
| OC sink current | locs | V _{IN} = 5.0 V, V _{OC} = 0.4 V | 2.0 | 5.0 | _ | mA | | |
| Current limit | Rым* | V _{IN} = 5.0 V (I _{SW} = 0.6 A) | 1.4 | 2.0 | 2.6 | kΩ | | |
| resistance | NLIM | V _{IN} = 5.0 V (I _{SW} = 0.1 A) | 3.6 | 6.2 | 9.1 | kΩ | | |
| Operating temperature | Тор | _ | -20 | _ | +85 | °C | | |

^{*:} For Css, Rlim settings, see "TYPICAL CHARACTERISTICS" and "FUNCTIONAL DESCRIPTION".

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS (per 1 ch)

• MB3842/MB3845 $(V_{IN} = 5 \text{ V}, \text{ Ta} = +25^{\circ}\text{C})$

| - WB3042/WB3043 | | Value |) v, ia = | | | |
|--|------------------|--|-----------|-------|------|------|
| Parameter | Symbol | Condition | | value | T | Unit |
| | | | Min. | Тур. | Max. | |
| Switch resistance | Ron | Isw =0.6A | _ | 100 | 150 | mΩ |
| | I _{IN1} | Isw = 0 A | _ | 350 | 550 | μΑ |
| IN pin input current | I _{IN2} | Isw = 0.6 A | _ | 1.0 | 1.5 | mA |
| in par adrient | Іімз | EN < 0.8V for MB3842, EN = V _{IN} for MB3845 | _ | _ | 1.0 | μΑ |
| LIVI O throubold | Viuh | V_{IN} at $OC = L \rightarrow H$ | 2.1 | 2.3 | 2.5 | V |
| UVLO threshold | VIUL | V_{IN} at $OC = H \rightarrow L$ | 1.9 | 2.1 | 2.3 | V |
| UVLO hysteresis width | Viuhy | VIUHY = VIUH - VIUL | 100 | 200 | 300 | mV |
| Curitab aurrant limit | Iswн | $R_{\text{LIM}} = 2.0 \text{ k}\Omega$ | 0.42 | 0.6 | 0.78 | Α |
| Switch current limit | IswL | $R_{\text{LIM}} = 6.2 \text{ k}\Omega$ | 0.06 | 0.1 | 0.14 | Α |
| OC sink current | locs | Voc = 0.4 V at OC active | 2.0 | 5.0 | _ | mA |
| OC Sink current | locL | Voc = 5.0 V at OC non-active | _ | _ | 1.0 | μΑ |
| Temperature protection (T _i) | TLIM | _ | +125 | _ | _ | °C |
| OUT pin rise time | ton | SS pin: Open OUT pin: 100 kΩ pull down | _ | 100 | 200 | μs |
| OUT pin fall time | toff | SS pin: Open OUT pin: 100 kΩ pull down | _ | 50 | 120 | μs |

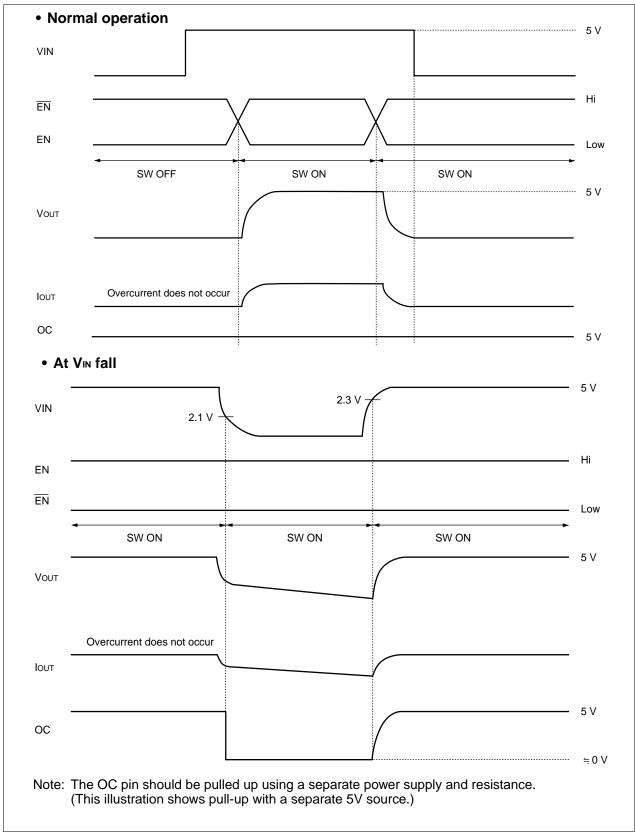
• MB3842 $(V_{IN} = 5 \text{ V}, \text{ Ta} = +25^{\circ}\text{C})$

| Parameter | Symbol | Condition | | Unit | | |
|-----------------------------|--------------|--|------|------|------|-------|
| Parameter | Symbol | Condition | Min. | Тур. | Max. | Ollit |
| ENABLE pin input current | I ENH | V _{EN} = 5 V, I _{SW} = 0 A | | 5 | 10 | μΑ |
| LIVABLE pili iliput cullent | IENL | V _{EN} = 0 V, I _{SW} = 0 A | _ | 0.0 | _ | μΑ |
| ENABLE pin threshold | VTHEN | _ | 1.45 | 1.60 | 1.75 | V |
| voltage | VTLEN | _ | 1.25 | 1.40 | 1.55 | V |
| ENABLE hysteresis width | VENHY | VENHY = VTHEN - VTLEN | 100 | 200 | 300 | mV |

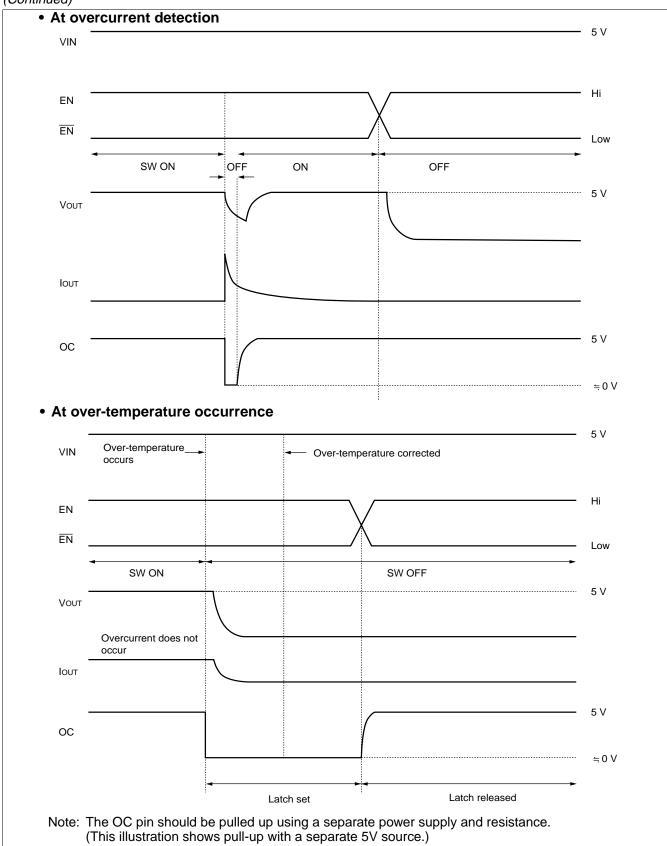
• MB3845 $(V_{IN} = 5 \text{ V, Ta} = +25^{\circ}\text{C})$

| Parameter | Symbol | Condition | | Value | Unit | |
|---------------------------|--------|--|-----|-------|------|------|
| Parameter | Symbol | ool Condition | | Тур. | | Max. |
| ENABLE pin input current | IENH | V _{EN} = 5 V, I _{SW} = 0 A | _ | 0.0 | _ | μΑ |
| ENABLE pin input current | IENL | V _{EN} = 0 V, I _{SW} = 0 A | _ | 0.0 | _ | μΑ |
| ENABLE pin input voltage | VILEN | _ | 0 | _ | 0.8 | V |
| LIVABLE pin input voitage | VIHEN | _ | 3.0 | _ | 5.0 | V |

■ DIAGRAM



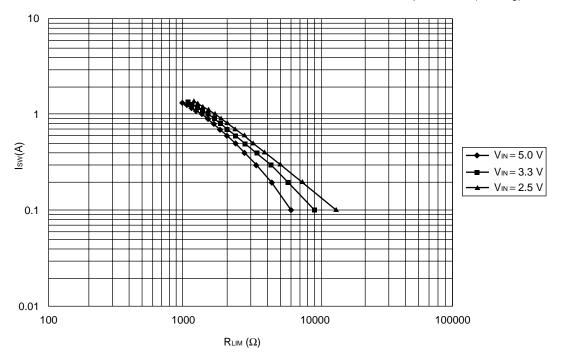
(Continued)



■ TYPICAL CHARACTERISTICS

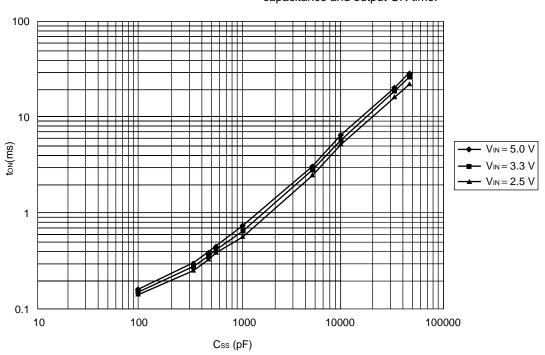
• RLIM vs. limit current characteristics

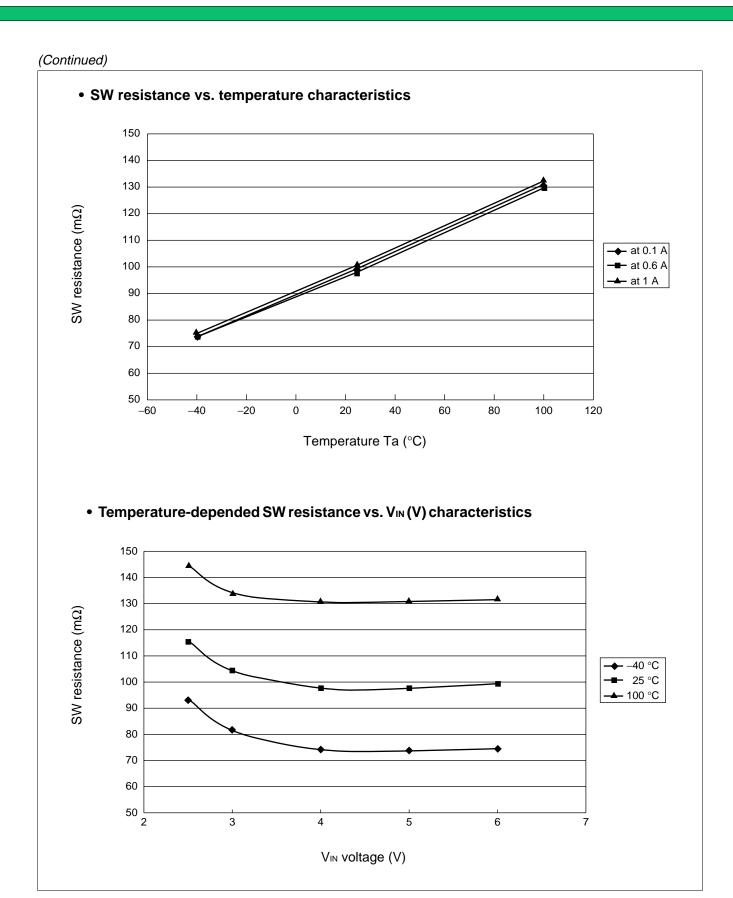
These are the limiting value characteristics for CS pin-to-GND external resistance and output current (OC flag).



• Css vs. Ton (SS) characteristics

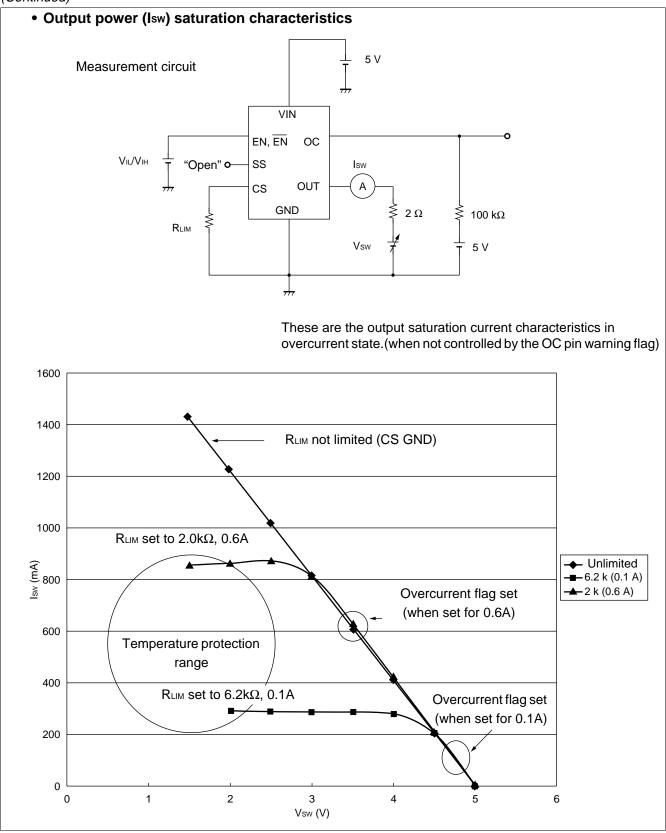
There are the characteristics for SS pin-to-GND external capacitance and output ON time.



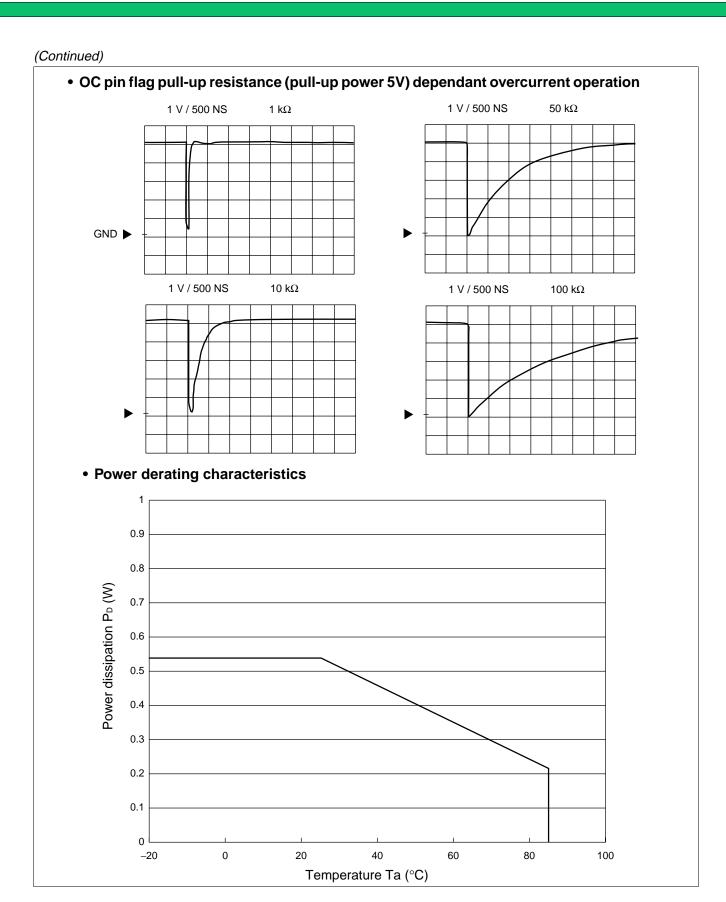


(Continued)

(Continued)



(Continued)



■ FUNCTIONAL DESCRIPTION

Current Limit Setting

By placing resistance between the CS and GND pins, the current limit can be set between 100mA and 600mA within $\pm 30\%$ accuracy ($V_{IN}=5$ V, current limit at 600mA). Because the setting value is dependent on V_{IN} voltage, the user should select the optimum resistance value for the value of V_{IN} voltage. When the switching current exceeds the set value, the OC pin goes to "L" level as an external notification signal, but there is no latching function. To hold operation on "off" state, the input signal to the EN and $\overline{\text{EN}}$ pins should be used.

When a direct connection to GND is used, there is no current limitation.

When the connection is open, the switch is in a state of continuously held current limits.

Thermal Shutdown

The MB3842/MB3845 has a thermal shutdown function which turns the switch off and sets the latch to protect the device when junction temperature exceeds 125°C.

At the same time the OC output signal goes to "L" level to notify external systems.

The latch function can be reset by sending a low signal to the EN input of the MB3842, or a high signal to the EN input of the MB3845.

Slow Start

The on/off switching time can be delayed by applying capacitance between the SS and GND pins. Controlling the on time can soften surge current to the load side capacitance when power is turned on. For details, see "Css vs. ton (SS) characteristics" on p. 9.

UVLO

A V_{IN} voltage monitoring function is provided, so that when V_{IN} voltage exceeds 2.3 V (typ) the OC pin voltage goes to "H" level. When V_{IN} voltage falls below 2.1V (typ), the OC output goes to "L" state.

Error Flag OC Pin

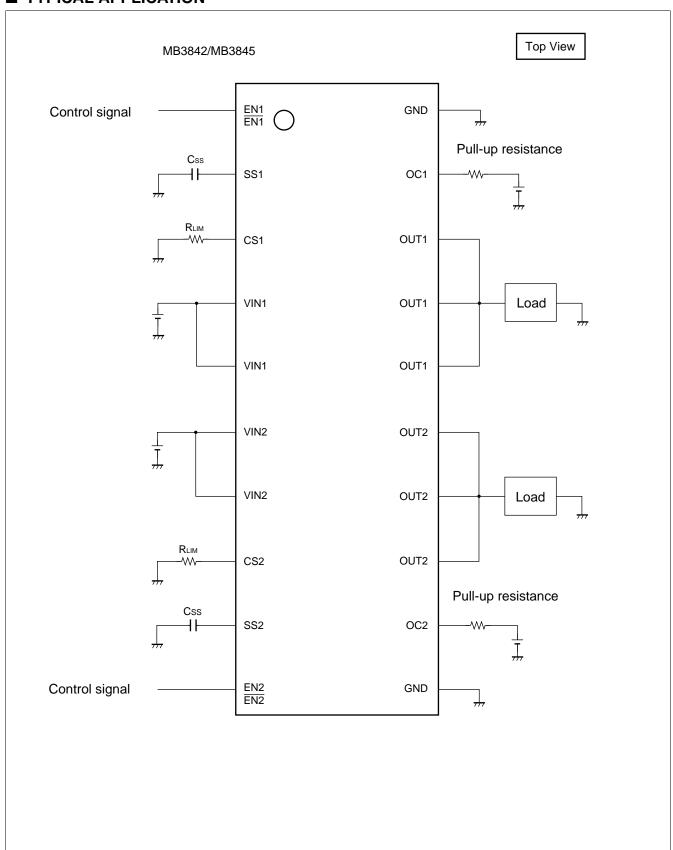
The OC pin produces a "L" signal in case of a UVLO, overcurrent, or over-temperature condition. In case of overcurrent, the output has a pulse waveform. See P12.

(note) Output current limit setting resistance values are shown on P9, and in the following table. (CS pin-to-GND)

Standard Values

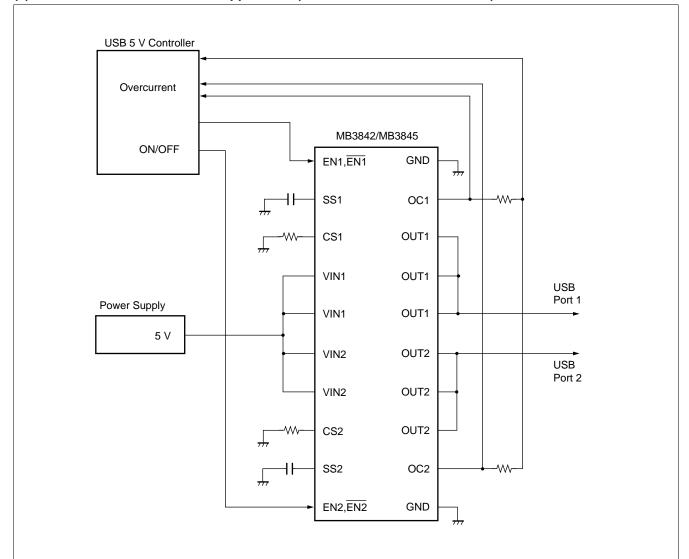
| V _{IN} /Isw | 0.1 A | 0.2 A | 0.3 A | 0.4 A | 0.5 A | 0.6 A | 0.7 A | 0.8 A | 0.9 A | 1.0 A |
|----------------------|--------|--------|------------------------|------------------------|--------|------------------------|------------------------|--------|--------|--------|
| Vin 5.0V | 6.2 kΩ | 4.3 kΩ | $3.3~\mathrm{k}\Omega$ | 2.7 kΩ | 2.2 kΩ | $2.0~\mathrm{k}\Omega$ | 1.8 kΩ | 1.6 kΩ | 1.4 kΩ | 1.3 kΩ |
| Vin 3.3V | 9.1 kΩ | 5.6 kΩ | 4.3 kΩ | $3.3~\mathrm{k}\Omega$ | 2.7 kΩ | 2.4 kΩ | $2.0~\mathrm{k}\Omega$ | 1.8 kΩ | 1.6 kΩ | 1.5 kΩ |
| Vin 2.5V | 13 kΩ | 7.5 kΩ | 5.1 kΩ | 3.9 kΩ | 3.0 kΩ | 2.7 kΩ | 2.2 kΩ | 2.0 kΩ | 1.8 kΩ | 1.6 kΩ |

■ TYPICAL APPLICATION



■ APPLICATION EXAMPLE

(1) Dual-Port Self-Powered Hub Application (NON-GANG Mode Connection)

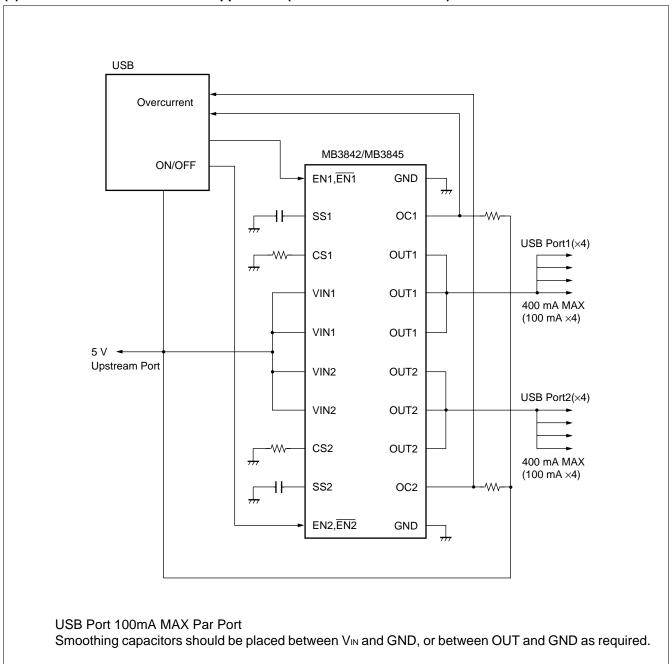


*The MB3842 can also be adapted for use with 3.3V controllers.

USB Port 500mA MAX Par Port

Smoothing capacitors should be placed between VIN and GND, or between OUT and GND as required.

(2) Dual-Port Bus Powered Hub Application (GANG Mode Connection)



■ USAGE PRECAUTION

1. Never use settings exceeding maximum rated conditions.

Exceeding maximum rated conditions may cause permanent damage to the LSI.

Also, it is recommended that recommended operating conditions be observed in normal use. Exceeding recommended operating conditions may adversely affect LSI reliability.

2. Use this device within recommended operating conditions.

Recommended operating conditions are values within which normal LSI operation is warranted.

Standard electrical characteristics are warranted within the range of recommended operating conditions and within the listed conditions for each parameter.

3. Printed circuit board ground lines should be set up with consideration for common impedance.

4. Take appropriate static electricity measures.

- Containers for semiconductor materials should have anti-static protection or be made of conductive material.
- After mounting, printed circuit boards should be stored and shipped in conductive bags or containers.
- Work platforms, tools, and instruments should be properly grounded.
- Working personnel should be grounded with resistance of 250 k Ω to 1 M Ω between body and ground.

5. Do not apply negative voltages.

The use of negative voltages below –0.3 V may create parasitic transistors on LSI lines, which can cause abnormal operation.

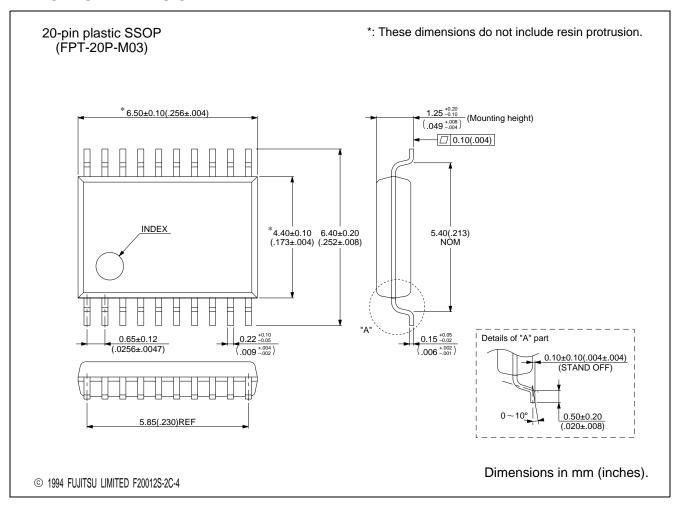
6. Reverse Current Prevention Function

Current cannot flow back to the V_{IN} pin with the switch off, even when the OUT pin voltage is higher than the V_{IN} pin (OUT $\geq V_{IN}$), however when V_{IN} pin voltage is lower than 1.5 V circuit functions are lost, so that in this case there is danger of reverse current flow. For applications in which reverse flow is not acceptable, set $V_{IN} \geq 1.5 \text{ V}$.

■ ORDERING INFORMATION

| Part number | Package | Remarks |
|--|--------------------------------------|---------|
| MB3842PFV MB3845PFV MB3845PFV-ER | 20-pin Plastic SSOP (FPT-20P-M03) | |

■ PACKAGE DIMENSION



FUJITSU LIMITED

For further information please contact:

Japan

FUJITSU LIMITED Corporate Global Business Support Division Electronic Devices KAWASAKI PLANT, 4-1-1, Kamikodanaka Nakahara-ku, Kawasaki-shi Kanagawa 211-8588, Japan

Tel: 81(44) 754-3763 Fax: 81(44) 754-3329

http://www.fujitsu.co.jp/

North and South America

FUJITSU MICROELECTRONICS, INC. Semiconductor Division 3545 North First Street San Jose, CA 95134-1804, USA

Tel: (408) 922-9000 Fax: (408) 922-9179

Customer Response Center Mon. - Fri.: 7 am - 5 pm (PST)

Tel: (800) 866-8608 Fax: (408) 922-9179

http://www.fujitsumicro.com/

Europe

FUJITSU MICROELECTRONICS EUROPE GmbH Am Siebenstein 6-10 D-63303 Dreieich-Buchschlag

D-63303 Dreieich-Buchschlag Germany

Tel: (06103) 690-0

Fax: (06103) 690-122

http://www.fujitsu-fme.com/

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE LTD #05-08, 151 Lorong Chuan New Tech Park Singapore 556741

Tel: (65) 281-0770 Fax: (65) 281-0220

http://www.fmap.com.sg/

F0001

© FUJITSU LIMITED Printed in Japan

All Rights Reserved.

The contents of this document are subject to change without notice. Customers are advised to consult with FUJITSU sales representatives before ordering.

The information and circuit diagrams in this document are presented as examples of semiconductor device applications, and are not intended to be incorporated in devices for actual use. Also, FUJITSU is unable to assume responsibility for infringement of any patent rights or other rights of third parties arising from the use of this information or circuit diagrams.

FUJITSU semiconductor devices are intended for use in standard applications (computers, office automation and other office equipment, industrial, communications, and measurement equipment, personal or household devices, etc.).

CAUTION:

Customers considering the use of our products in special applications where failure or abnormal operation may directly affect human lives or cause physical injury or property damage, or where extremely high levels of reliability are demanded (such as aerospace systems, atomic energy controls, sea floor repeaters, vehicle operating controls, medical devices for life support, etc.) are requested to consult with FUJITSU sales representatives before such use. The company will not be responsible for damages arising from such use without prior approval.

Any semiconductor devices have an inherent chance of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions.

If any products described in this document represent goods or technologies subject to certain restrictions on export under the Foreign Exchange and Foreign Trade Law of Japan, the prior authorization by Japanese government will be required for export of those products from Japan.